

## MAX40075/MAX40088

## 10MHz/42MHz Low-Noise, Low-Bias Op Amps

### General Description

The MAX40075/MAX40088 are wideband, low-noise, low-input bias current operational amplifiers offering rail-to-rail outputs and single-supply operation down to 2.7V. They draw 2.2mA of quiescent supply current per amplifier when enabled and have ultra-low distortion (0.0002% THD+N), as well as low input voltage-noise density ( $4.2\text{nV}/\sqrt{\text{Hz}}$ ) and low input current-noise density ( $0.5\text{fA}/\sqrt{\text{Hz}}$ ). The low input bias current and low noise together with the wide bandwidth suit transimpedance amplifiers and imaging applications.

For power conservation, the MAX40075/MAX40088 offer a low-power shutdown mode that reduces supply current to  $0.1\mu\text{A}$  and places the amplifiers outputs into a high impedance state. These amplifiers have outputs which swing rail-to-rail and their input common-mode voltage range includes ground. The MAX40075 is unity-gain stable with a gain-bandwidth product of 10MHz. The MAX40088 is gain-of-5 stable with a gain-bandwidth product of 42MHz.

### Applications

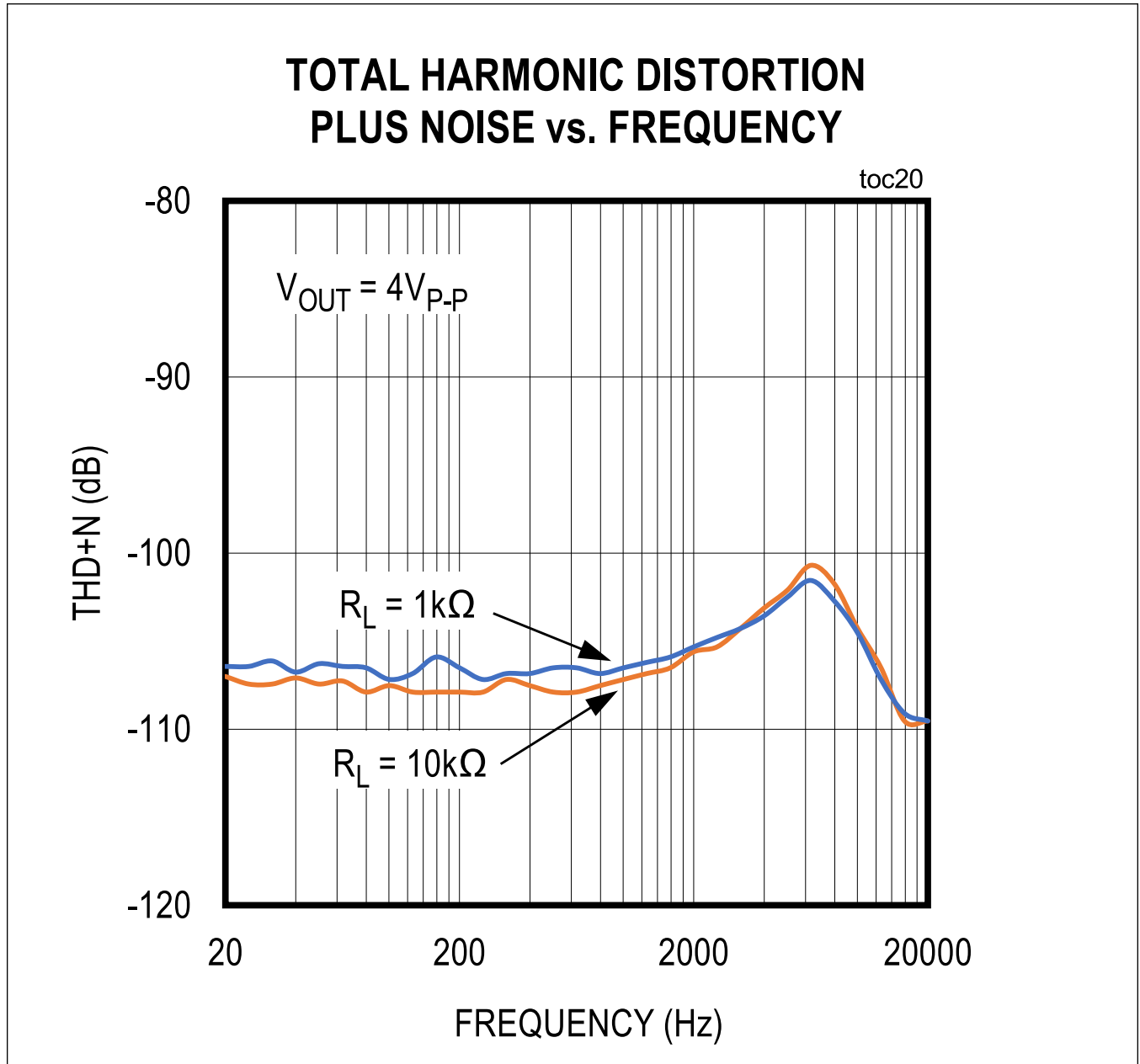
- ADC Buffers
- DAC Output Amplifiers
- Low-Noise Microphone/Preamplifiers
- Digital Scales
- Strain Gauges/Sensor Amplifiers
- Transimpedance Amplifiers
- Medical Instrumentation
- Automotive Power Train

### Benefits and Features

- Low Input Voltage-Noise Density:  $4.2\text{nV}/\sqrt{\text{Hz}}$  at 30kHz
- Low Input Current-Noise Density:  $0.5\text{fA}/\sqrt{\text{Hz}}$
- Low Input Bias Current:  $<1\text{pA}$  (typ)
- Low Distortion: 0.00035% or -109dB THD+N (1k $\Omega$  Load)
- Single-Supply Operation from +2.7V to +5.5V
- Input Common-Mode Voltage Range Includes Ground
- Rail-to-Rail Output Swings with a 1k $\Omega$  Load
- 10MHz GBW Product, Unity-Gain Stable (MAX40075 Only)
- 42MHz GBW Product, Gain  $\geq 5\text{V/V}$  (MAX40088 Only)
- Excellent DC Characteristics: Input  $V_{\text{OS}} \leq 30\mu\text{V}$
- Low-Power Shutdown Mode: Reduces Supply Current to  $\leq 1\mu\text{A}$
- Available in Space-Saving 6-Bump WLP and 6-Pin SOT23 Packages
- AEC-Q100 Qualified, See [Ordering Information](#)

[Ordering Information](#) appears at end of data sheet.

THD+N Performance



## Absolute Maximum Ratings

Input Differential Voltage .....		Operating Temperature Range .....	-40°C to +125°C
MAX40075/MAX40088 (continuous) .....	-3V to +3V	Continuous Power Dissipation .....	
MAX40075/MAX40088 (transient, 10s) .....	-6V to +6V	6-Pin SOT23 (derate 8.7mW/°C at +70°C) .....	696mW
Power-Supply Voltage ( $V_{DD}$ to $V_{SS}$ ) .....	-0.3V to +6V	6-Bump WLP (derate 10.19mW/°C at +70°C) .....	815mW
Analog Input Voltage ( $IN+$ , $IN-$ ) .....	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V$	Storage Temperature Range .....	-65°C to +150°C
SHDN Input Voltage (SHDN) .....	$V_{SS} + 0.3V$ to +6V	Lead Temperature (soldering, 10s) .....	+300°C
Continuous Input Current ( $IN+$ , $IN-$ ) .....	$\pm 20mA$	Soldering Temperature (reflow) .....	+260°C
Output Short-Circuit Duration to Either Supply .....	Continuous		

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Package Information

### 6 SOT23

Package Code	U6+1, U6+1A
Outline Number	<a href="#">21-0058</a>
Land Pattern Number	<a href="#">90-0175</a>
<b>THERMAL RESISTANCE, SINGLE-LAYER BOARD</b>	
Junction to Ambient ( $\theta_{JA}$ )	N/A
Junction to Case ( $\theta_{JC}$ )	80°C/W
<b>THERMAL RESISTANCE, FOUR-LAYER BOARD</b>	
Junction to Ambient ( $\theta_{JA}$ )	115°C/W
Junction to Case ( $\theta_{JC}$ )	80°C/W

### 6 WLP

Package Code	N60F1+1
Outline Number	<a href="#">21-100174</a>
Land Pattern Number	Refer to <a href="#">Application Note 1891</a>
<b>THERMAL RESISTANCE, SINGLE-LAYER BOARD</b>	
Junction to Ambient ( $\theta_{JA}$ )	98.06°C/W
Junction to Case ( $\theta_{JC}$ )	N/A

For the latest package outline information and land patterns (footprints), go to [www.maximintegrated.com/packages](http://www.maximintegrated.com/packages). Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to [www.maximintegrated.com/thermal-tutorial](http://www.maximintegrated.com/thermal-tutorial).

## Electrical Characteristics

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = 2.5V$ ,  $\overline{SHDN} = V_{DD}$ ,  $V_{OUT} = V_{DD}/2$ ,  $R_L = \text{tied to } V_{DD}/2$ ,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ . ([Note 1](#)))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage Range	$V_{DD}$	Guaranteed by PSRR test	2.7		5.5	V

### Electrical Characteristics (continued)

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = 2.5V$ ,  $\overline{SHDN} = V_{DD}$ ,  $V_{OUT} = V_{DD}/2$ ,  $R_L = \text{tied to } V_{DD}/2$ ,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ . (Note 1))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Quiescent Supply Current, per Amplifier	$I_{DD}$	$V_{DD} = 3.3V$		2.2	3.0	mA
		$V_{DD} = 5V$		2.5	3.3	
Power-Up Time		$V_{DD} = 0$ to $5V$ step, $V_{OUT} = 2.5V \pm 1\%$		13		$\mu\text{s}$
Shutdown Supply Current	$I_{\overline{SHDN}}$	Over temperature, to $+125^\circ\text{C}$		0.4	1.7	$\mu\text{A}$
Input Offset Voltage	$V_{OS}$	At $+25^\circ\text{C}$		30	150	$\mu\text{V}$
		Over the full temperature range			450	
Input Offset Drift	$V_{OS-TC}$	Over temperature, to $+125^\circ\text{C}$		0.3	3	$\mu\text{V}/^\circ\text{C}$
Input Bias Current (Note 2)	$I_B$			1	2300	pA
Input Offset Current (Note 2)	$I_{OS}$			0.2	500	pA
Differential Input Resistance	$R_{IN}$			1000		$\text{G}\Omega$
Input Capacitance	$C_{IN}$	Either input, over entire CMIR		10		pF
Input Common-Mode Range	$V_{IN+}, V_{IN-}$	Guaranteed by CMRR test, at $+25^\circ\text{C}$	-0.2		$V_{DD} - 1.5$	V
		Guaranteed by CMRR test, full temperature range	-0.1		$V_{DD} - 1.5$	
Common-Mode Rejection Ratio	CMRR	DC, $-0.2V < \text{CMIR} < V_{DD} - 1.5V$ , at $+25^\circ\text{C}$	90	109		dB
		DC, $-0.1V < \text{CMIR} < V_{DD} - 1.5V$ , full temperature range	89			
Common-Mode Rejection Ratio, AC	CMRR	100mV <sub>P-P</sub> 1MHz, with DC in 0V to $V_{DD} - 2V$ range		60		dB
Power-Supply Rejection Ratio, DC	PSRR	DC, $2.7V < V_{DD} < 5.5V$	90	107		dB
Power-Supply Rejection Ratio, AC	PSRR	AC, 100mV <sub>P-P</sub> 1MHz, superimposed on $V_{DD}$		40		dB
Open-Loop Gain	$A_{OL}$	$R_L = 10\text{k}\Omega$ to $V_{DD}/2$ , $V_{OUT} = 200\text{mV}$ to $V_{DD} - 250\text{mV}$	93	114		dB
		$R_L = 1\text{k}\Omega$ to $V_{DD}/2$ , $V_{OUT} = 200\text{mV}$ to $V_{DD} - 250\text{mV}$	87	109		
		$R_L = 500\Omega$ to $V_{DD}/2$ , $V_{OUT} = 200\text{mV}$ to $V_{DD} - 250\text{mV}$	85	107		
Output Voltage Swing High	$V_{DD} - V_{OH}$	$R_L = 10\text{k}\Omega$ to $V_{DD}/2$ , $V_{DD} - V_{OH}$		3	10	mV
		$R_L = 1\text{k}\Omega$ to $V_{DD}/2$ , $V_{DD} - V_{OH}$		30	60	
		$R_L = 500\Omega$ to $V_{DD}/2$ , $V_{DD} - V_{OH}$		60	120	
Output Voltage Swing Low	$V_{OL}$	$R_L = 10\text{k}\Omega$ to $V_{DD}/2$ , $V_{DD} - V_{SS}$		3	10	mV
		$R_L = 1\text{k}\Omega$ to $V_{DD}/2$ , $V_{OL} - V_{SS}$		30	60	
		$R_L = 500\Omega$ to $V_{DD}/2$ , $V_{OL} - V_{SS}$		60	120	

**Electrical Characteristics (continued)**

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = 2.5V$ ,  $\overline{SHDN} = V_{DD}$ ,  $V_{OUT} = V_{DD}/2$ ,  $R_L = \text{tied to } V_{DD}/2$ ,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ . (Note 1))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Short-Circuit Current	$I_{SC}$	Shorted to either power supply		48		mA
Output Leakage Current When Shut Down		$V_{SS} < V_{OUT} < V_{DD}$		0.01	1	$\mu\text{A}$
Shutdown Input Low Level					$0.3 \times V_{DD}$	V
Shutdown Input High Level			$0.7 \times V_{DD}$			V
Shutdown Input Bias				0.01	1	$\mu\text{A}$
-3dB Bandwidth (BW)		Unity-gain version, $A_V = +1$		10		MHz
		Gain of 5 stable, $A_V = +5$		42		
Phase Margin	$\Phi_m$	Unity-gain version, $A_V = +1$		70		°
		Gain of 5 stable, $A_V = +5$		80		
Gain Margin	GM			12		dB
Slew Rate	SR	Unity-gain version, $A_V = +1$		3		V/ $\mu\text{s}$
		Gain of 5 stable, $A_V = +5$		10		
Settling Time		Unity-gain version, $A_V = +1$ , to 0.01%, $V_{OUT} = 2V$ step		2		$\mu\text{s}$
		Gain of 5 stable, $A_V = +5$ , to 0.01%, $V_{OUT} = 2V$ step		2		
Stable Capacitive Load	$C_{LOAD}$	Guaranteed stability over all conditions		50		pF
Integrated 1/f Input Voltage Noise		0.1Hz to 10Hz		1.7		$\mu\text{V}_{P-P}$
Input Voltage Noise Density	$V_N$	f = 10Hz		260		nV/ $\sqrt{\text{Hz}}$
		f = 1kHz		5.5		
		f = 30kHz		4.2		
Input Current Noise Density	$I_N$	f = 1kHz		0.5		fA/ $\sqrt{\text{Hz}}$

**Electrical Characteristics (continued)**

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = 2.5V$ ,  $\overline{SHDN} = V_{DD}$ ,  $V_{OUT} = V_{DD}/2$ ,  $R_L = \text{tied to } V_{DD}/2$ ,  $T_A = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted. Typical values are at  $T_A = +25^\circ\text{C}$ . (*Note 1*))

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Total Harmonic Distortion + Noise	THD+N	Unity-gain version, $A_V = +1$ , $V_{OUT} = 4V_{P-P}$ , 10k $\Omega$ to GND, 1kHz		-114.0		dBc
		Unity-gain version, $A_V = +1$ , $V_{OUT} = 4V_{P-P}$ , 10k $\Omega$ to GND, 20kHz		-103.1		
		Unity-gain version, $A_V = +1$ , $V_{OUT} = 4V_{P-P}$ , 1k $\Omega$ to GND, 1kHz		-114.0		
		Unity-gain version, $A_V = +1$ , $V_{OUT} = 4V_{P-P}$ , 1k $\Omega$ to GND, 20kHz		-100.0		
		Gain of 5 version, $A_V = +5$ , $V_{OUT} = 4V_{P-P}$ , 10k $\Omega$ to GND, 1kHz		-108.0		
		Gain of 5 version, $A_V = +5$ , $V_{OUT} = 4V_{P-P}$ , 10k $\Omega$ to GND, 20kHz		-110		
		Gain of 5 version, $A_V = +5$ , $V_{OUT} = 4V_{P-P}$ , 1k $\Omega$ to GND, 1kHz		-106.0		
		Gain of 5 version, $A_V = +5$ , $V_{OUT} = 4V_{P-P}$ , 1k $\Omega$ to GND, 20kHz		-110		
Electromagnetic Interference Rejection Ratio	EMIRR	$V_{RF\_PP} = 100\text{mV}$ , $f = 900\text{MHz}$ to 2400MHz		55		dB

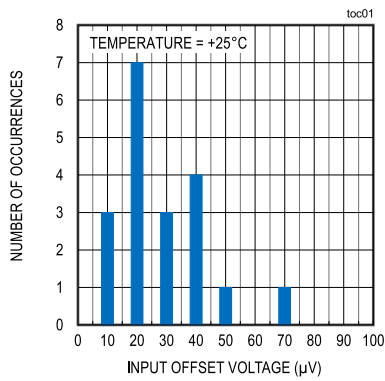
**Note 1:** Limits are 100% tested at  $T_A = +25^\circ\text{C}$ . Limits over the operating temperature range and relevant supply voltage range are guaranteed by design and characterization.

**Note 2:** Guaranteed by design and bench characterization.

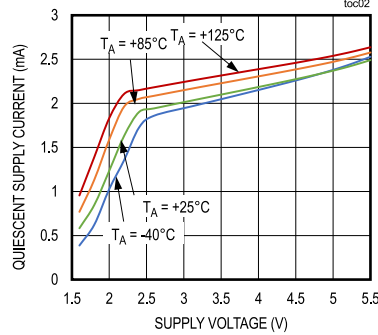
Typical Operating Characteristics

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = V_{DD}/2$ ,  $R_L = 10k\Omega$  to  $V_{DD}/2$ ,  $C_L = 10pF$  to GND,  $T_A = +25^\circ C$ , unless otherwise noted.)

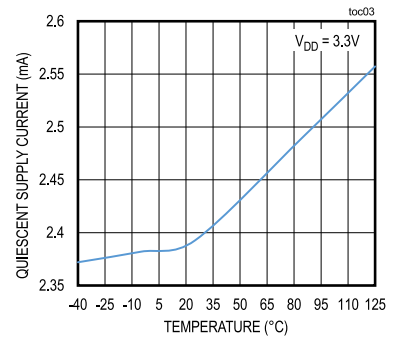
INPUT OFFSET VOLTAGE HISTOGRAM



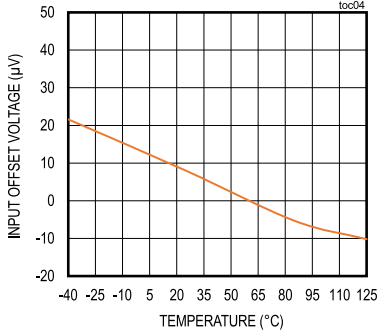
SUPPLY CURRENT vs. SUPPLY VOLTAGE



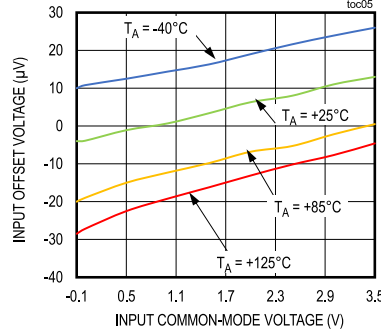
SUPPLY CURRENT vs. TEMPERATURE



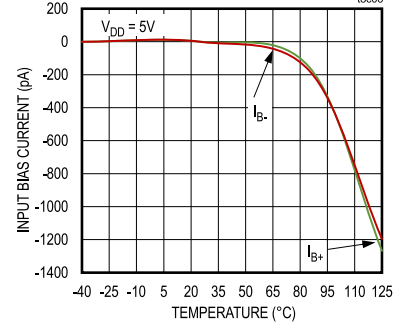
INPUT OFFSET VOLTAGE vs. TEMPERATURE



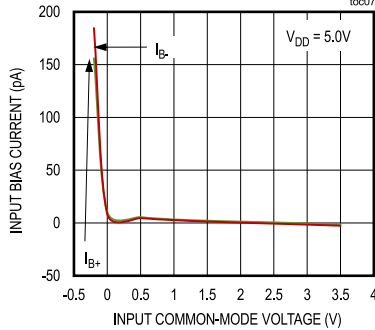
INPUT OFFSET VOLTAGE vs. INPUT COMMON-MODE VOLTAGE



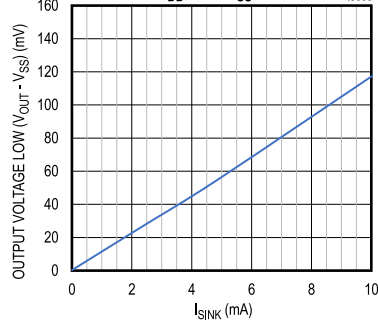
INPUT BIAS CURRENT vs. TEMPERATURE



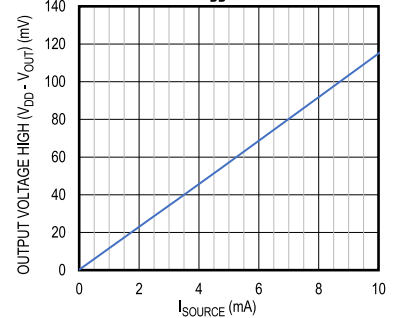
INPUT BIAS CURRENT vs. INPUT COMMON-MODE VOLTAGE



OUTPUT VOLTAGE LOW vs. OUTPUT SINK CURRENT

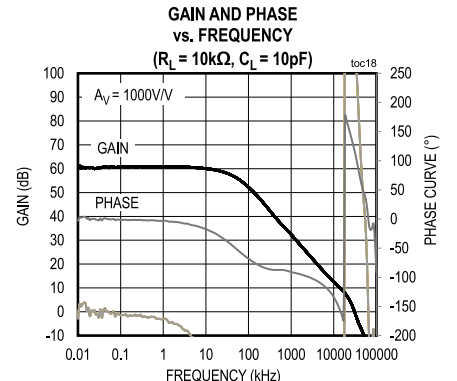
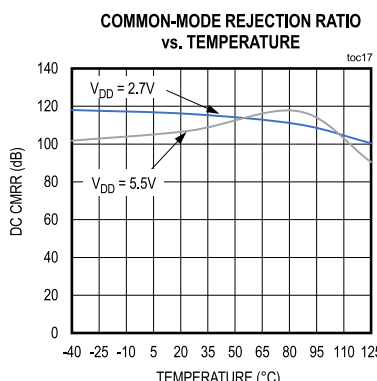
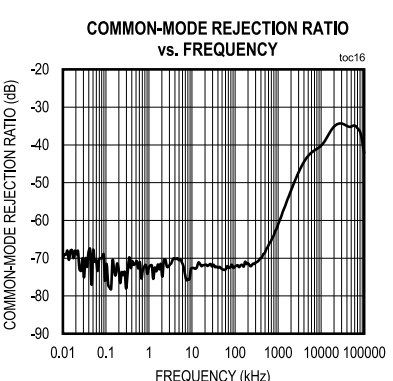
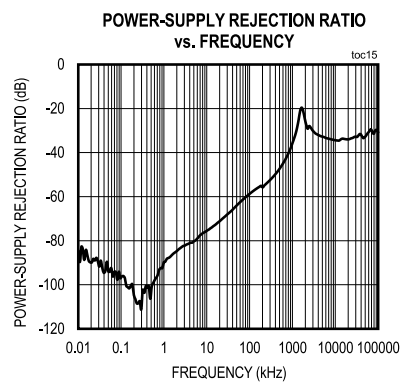
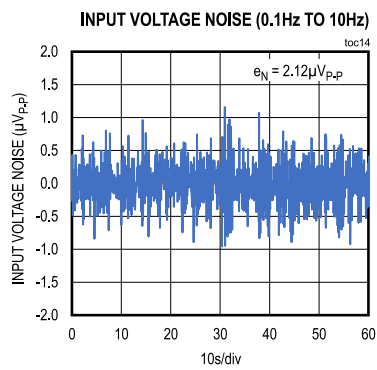
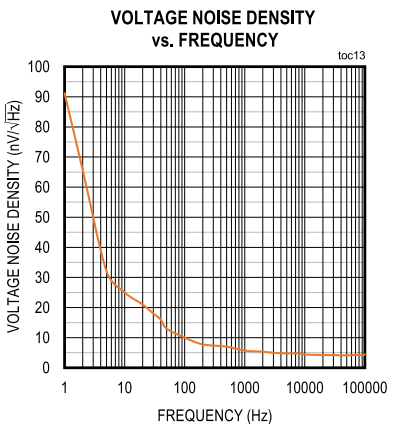
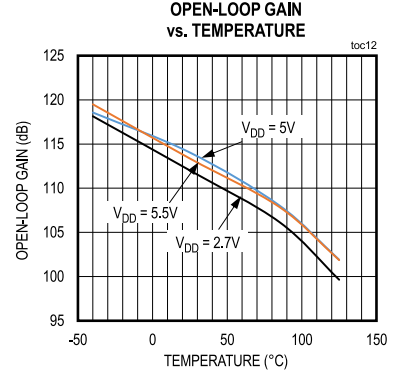
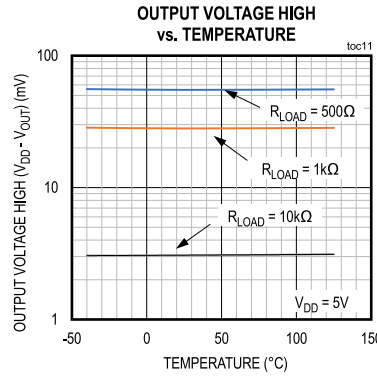
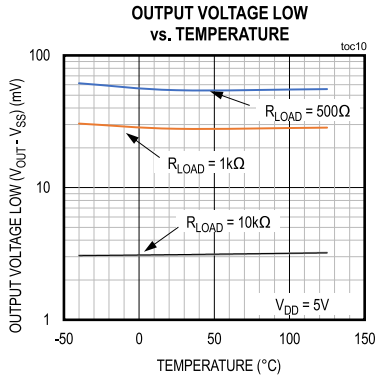


OUTPUT VOLTAGE HIGH vs. OUTPUT SOURCE CURRENT



Typical Operating Characteristics (continued)

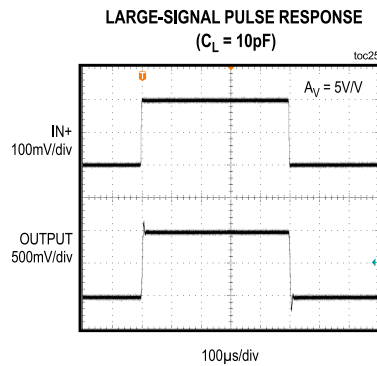
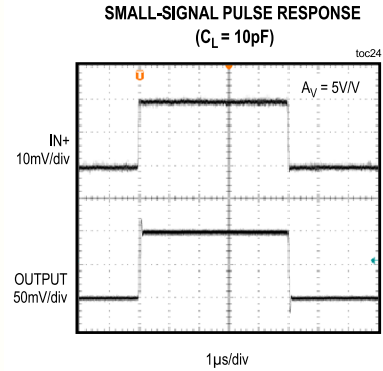
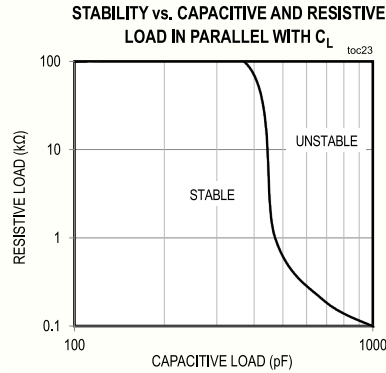
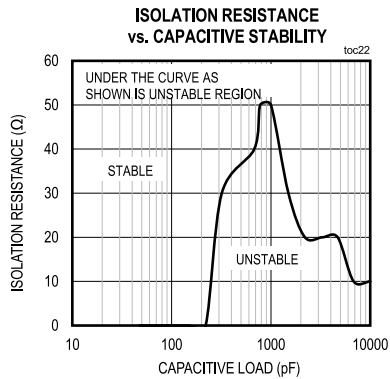
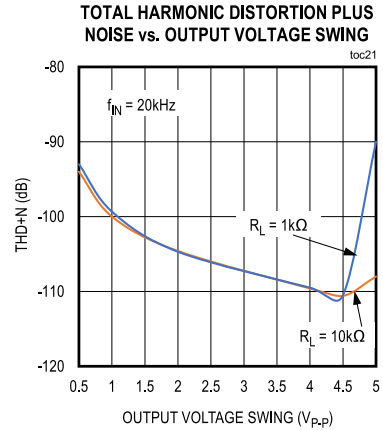
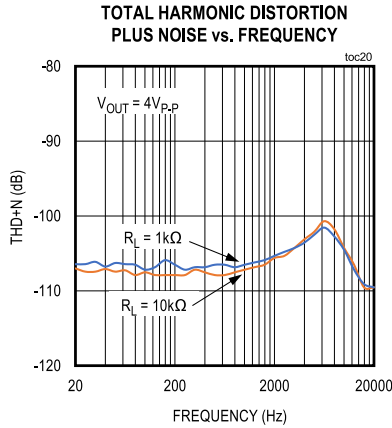
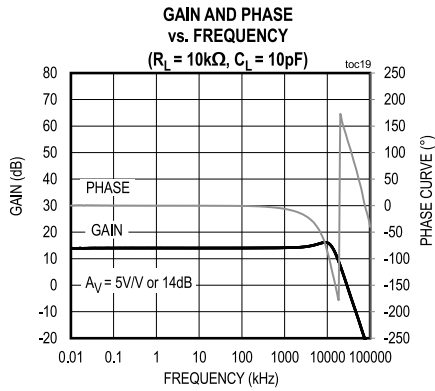
( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = V_{DD}/2$ ,  $R_L = 10k\Omega$  to  $V_{DD}/2$ ,  $C_L = 10pF$  to GND,  $T_A = +25^\circ C$ , unless otherwise noted.)



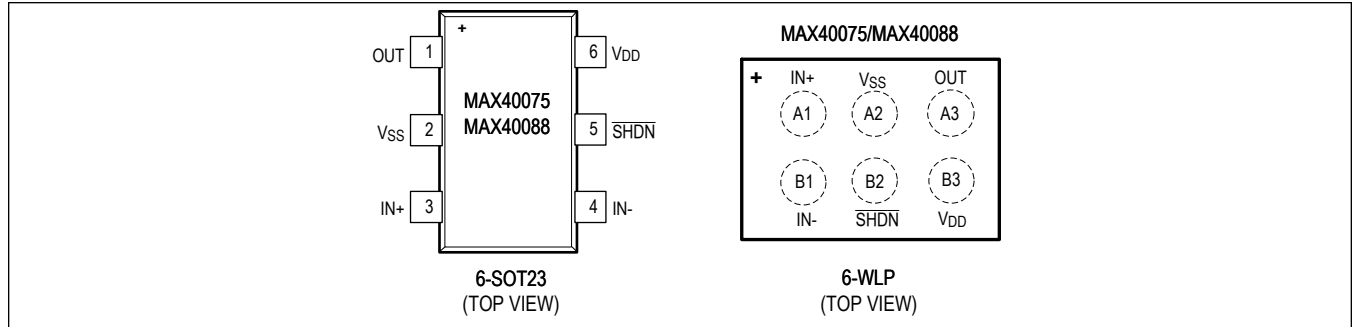


Typical Operating Characteristics (continued)

( $V_{DD} = +5V$ ,  $V_{SS} = 0V$ ,  $V_{CM} = V_{DD}/2$ ,  $R_L = 10k\Omega$  to  $V_{DD}/2$ ,  $C_L = 10pF$  to GND,  $T_A = +25^\circ C$ , unless otherwise noted.)



Pin Configurations

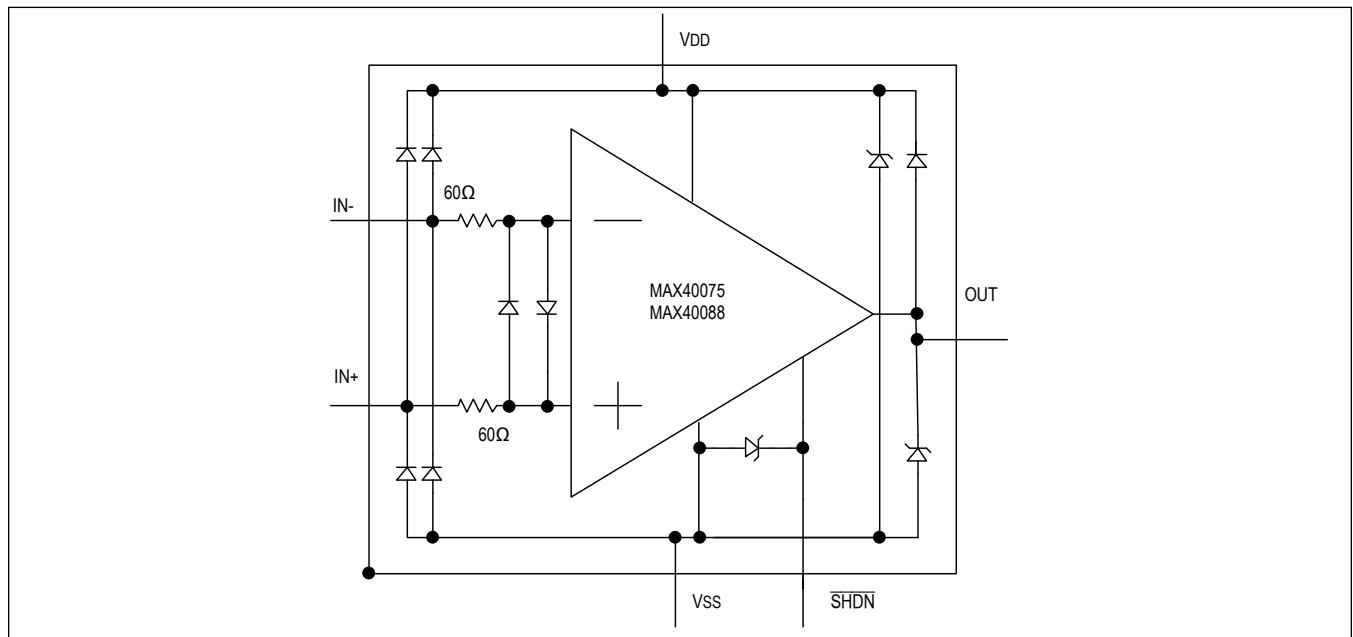


Pin Description

PIN		NAME	FUNCTION
6 SOT23	6 WLP		
1	A3	OUT	Amplifier Output
2	A2	VSS	Negative Supply. Connect to ground for single-supply operation.
3	A1	IN+	Non-Inverting Amplifier Input
4	B1	IN-	Inverting Amplifier Input
5	B2	SHDN	Shutdown, Active Low. Connect to VDD for normal operation (amplifier enabled).
6	B3	VDD	Positive Supply. Connect 0.1μF and 4.7μF from VDD to VSS.

Functional Diagrams

Internal ESD Protection



## Detailed Description

The MAX40075/MAX40088 single-supply operational amplifiers feature ultra-low noise and distortion. Their low distortion and low noise make them ideal for use as pre-amplifiers in wide dynamic range applications, such as 16-bit analog-to-digital converters. Their high input impedance and low noise are also useful for signal conditioning of high-impedance sources, such as piezoelectric transducers.

These devices have true rail-to-rail output operation, drive output resistive loads as low as 1k $\Omega$  while maintaining DC accuracy and can drive capacitive loads up to 200pF without any oscillation. The input common-mode voltage range extends from 0.2V below  $V_{SS}$  to ( $V_{DD} - 1.5V$ ). The push-pull output stage maintains excellent DC characteristics, while delivering up to  $\pm 20$  mA of source/sink output current.

The MAX40075 is unity-gain stable, while the MAX40088 is a decompensated version that has higher slew rate and is stable for gain  $\geq 5V/V$ . Both devices feature a low-power shutdown mode, which reduces the supply current to 0.1 $\mu$ A and places amplifiers outputs into a high-impedance state.

### Low Noise

The amplifiers input-referred voltage noise density is dominated by flicker noise (also known as 1/f noise) at lower frequencies and by thermal noise at higher frequencies. Overall thermal noise contribution is affected by the parallel combination of resistive feedback network ( $R_F || R_G$ ) depicted in [Figure 1](#). These resistors should be reduced in cases where system bandwidth is large and thermal noise is dominant. Noise contribution factor can be reduced with increased gain settings.

For example, the input noise voltage density ( $e_N$ ) of the circuit with  $R_F = 100k\Omega$ ,  $R_G = 10k\Omega$  (in [Figure 1](#)) with gain = 10V/V. The non-inverting configuration is  $e_N = 12nV/\sqrt{Hz}$ .  $e_N$  can be reduced to 6nV/ $\sqrt{Hz}$  by choosing  $R_F = 10k\Omega$ ,  $R_G = 1k\Omega$  (in [Figure 1](#)) with gain = 10V/V, as before, but at the expense of higher current consumption and higher distortion. Having a gain of 100V/V with  $R_F = 100k\Omega$ ,  $R_G = 1k\Omega$  (in [Figure 1](#)), input referred voltage noise density is still a low 6nV/ $\sqrt{Hz}$ .

### Low Distortion

Many factors can affect the noise and distortion performance of the amplifier based on the design choices made. The following guidelines offer valuable information on the impact of design choices on total harmonic distortion (THD). Choosing correct feedback and gain resistor values for a particular application can be a very important factor in reducing THD. In general, the smaller the closed-loop gain, the smaller the THD generated, especially when driving heavy resistive loads (e.g., smaller resistive load with higher output current). Operating the device near or above the full-power bandwidth significantly degrades distortion.

Referencing the load to either supply also improves the amplifier distortion performance, because only one of the MOSFETs of the push-pull output stage drives the output. Referencing the load to mid-supply increases the amplifier distortion for a given load and feedback setting (see the *Total Harmonic Distortion vs. Frequency* graph in [Typical Operating Characteristics](#)).

For gains  $\geq 5V/V$ , the decompensated MAX40088 delivers the best distortion performance as it has a higher slew rate and provides a higher amount of loop gain for a given closed-loop gain setting. Capacitive loads below 100pF do not significantly affect distortion results. Distortion performance is relatively constant over supply voltages.

### Using a Feed-Forward Compensation Capacitor, $C_Z$

The amplifier's input capacitance is 10pF, and if the resistance seen by the inverting input is large (in [Figure 1](#)) as a result of the feedback network, this resistance and capacitance combination can introduce a pole within the amplifier's bandwidth resulting in reduced phase margin. Compensate the reduced phase margin by introducing a feed-forward capacitor ( $C_Z$ ) between the inverting input and the output (shown in [Figure 1](#)). This effectively cancels the pole from the inverting input of the amplifier. Choose the value of  $C_Z$  as follows:

$$C_Z = 10 \times (R_F / R_G) [\text{pF}]$$

In the unity-gain stable MAX40075, the use of the correct  $C_Z$  is most important for closed-loop non-inverting gain  $A_V =$

+2V/V and inverting gain  $A_V = -1V/V$ .

In the decompensated MAX40088,  $C_Z$  is most important for closed-loop gain  $A_V = +10V/V$ .

Using a slightly smaller  $C_Z$  than suggested by the formula above achieves a higher bandwidth at the expense of reduced phase and gain margin. As a general guideline, consider using  $C_Z$  for cases where  $R_G || R_F$  is greater than 20k $\Omega$  (for the MAX40075) and greater than 5k $\Omega$  (for the MAX40088).

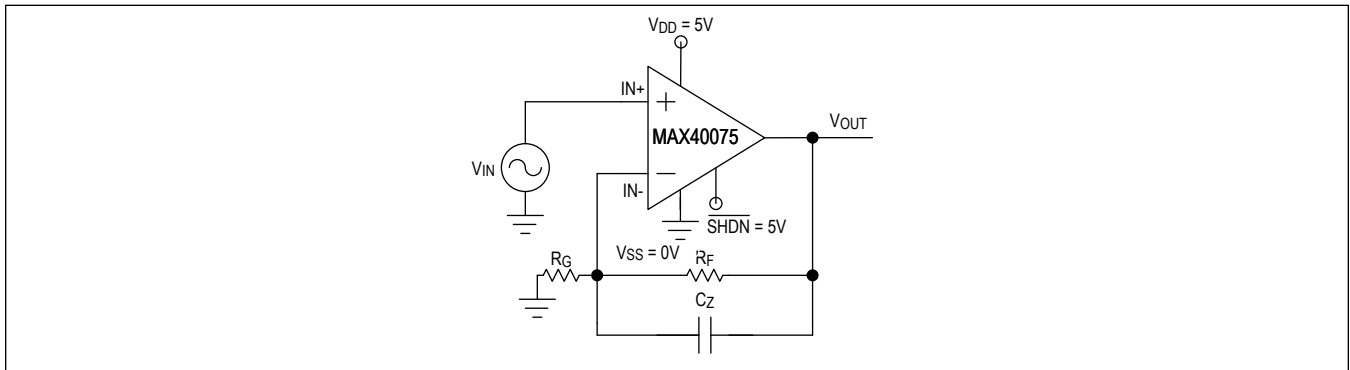


Figure 1. Adding Feed-Forward Compensation

## Applications Information

The MAX40075/MAX40088 combine good driving capability with ground-sensing input and rail-to-rail output operation. With their low distortion and low noise, these devices are ideal for use in ADC buffers, DAC output buffers, medical instrumentation systems, and other noise-sensitive applications.

### Ground-Sensing and Rail-to-Rail Outputs

The common-mode input range of these devices extends below ground over temperature that offers excellent common-mode rejection and can be used in low-side current sensing applications. These devices are guaranteed not to undergo phase reversal when the input is overdriven over input common-mode voltage range as shown in [Figure 2](#).

[Figure 3](#) showcases the true rail-to-rail output operation of the amplifier, configured with  $A_V = 5V/V$ . The output swings to within 8mV of the supplies with a 10k $\Omega$  load, making the devices ideal in low-supply voltage applications.

### Power Supplies and Layout

The MAX40075/MAX40088 operate from a single +2.7V to +5.5V power supply or from dual supplies of  $\pm 1.35V$  to  $\pm 2.75V$ . For single-supply operation, bypass the  $V_{DD}$  power supply pin with a 0.1 $\mu F$  ceramic capacitor placed close to the  $V_{DD}$  pin. If operating from dual supplies, bypass both of the  $V_{DD}$  and  $V_{SS}$  supply pins with a 0.1 $\mu F$  ceramic capacitor to ground. If additional decoupling is needed, add another 4.7 $\mu F$  or 10 $\mu F$  where the supply voltage is applied on the PCB.

Good layout improves performance by decreasing the amount of stray capacitance and noise at the op amp inputs and output. To decrease stray capacitance, minimize PC board trace lengths and resistor leads, and place external components close to the op amp's pins.

### Typical Application Circuit

The [Typical Application Circuit](#) shows a single MAX40075 configured as an output buffer for the MAX5541 16-bit DAC. Because the MAX5541 has an unbuffered voltage output, the input bias current of the op amp used must be less than 6nA to maintain 16-bit accuracy. This family of amplifiers has an input bias current of only 2.3nA (max) over temperature, virtually eliminating this as a source of error. In addition, the MAX40075 has excellent open-loop gain and common-mode rejection, making this an excellent output buffer amplifier.

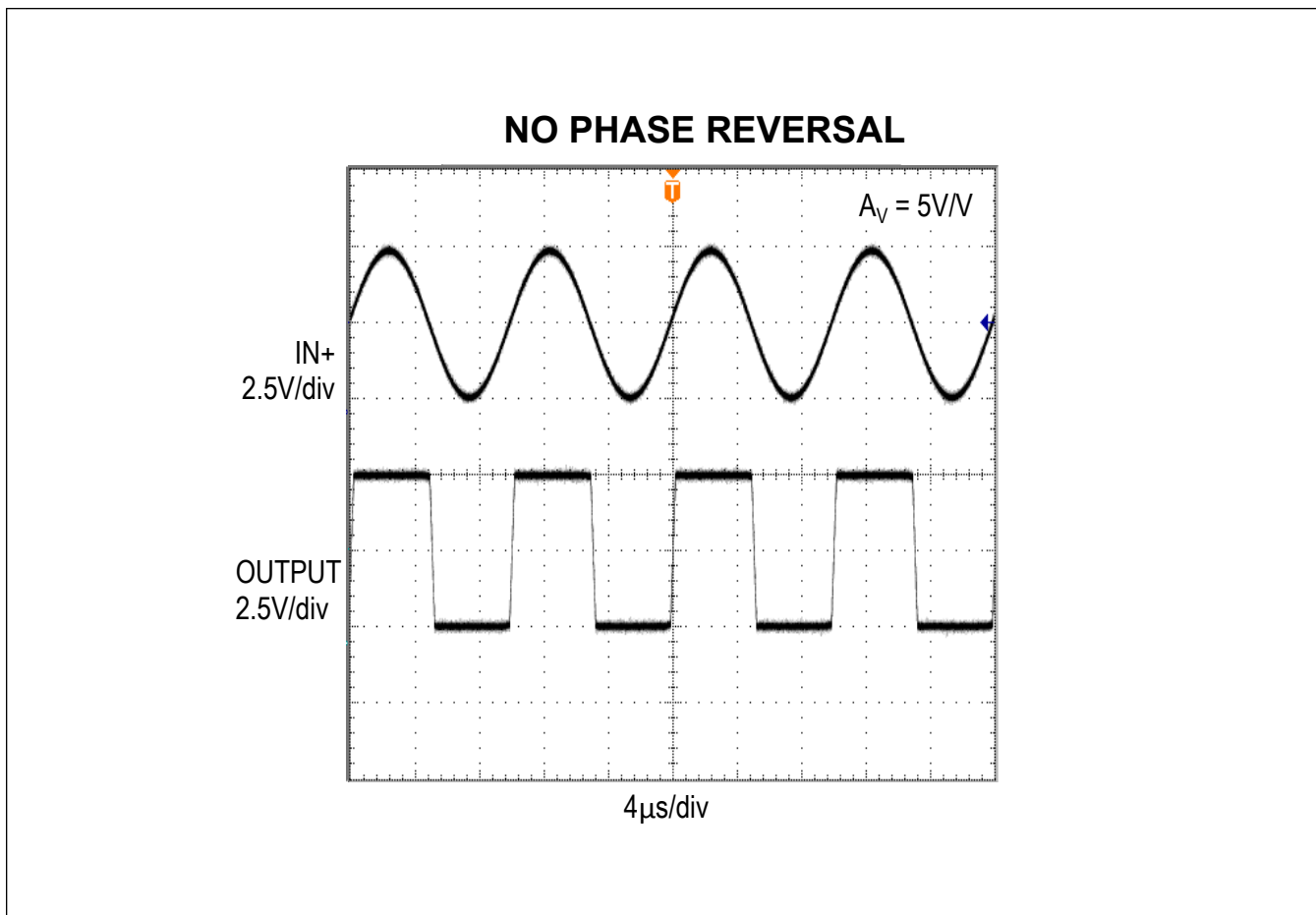


Figure 2. Scope Plot Showing Overdriven Input with No Phase Reversal

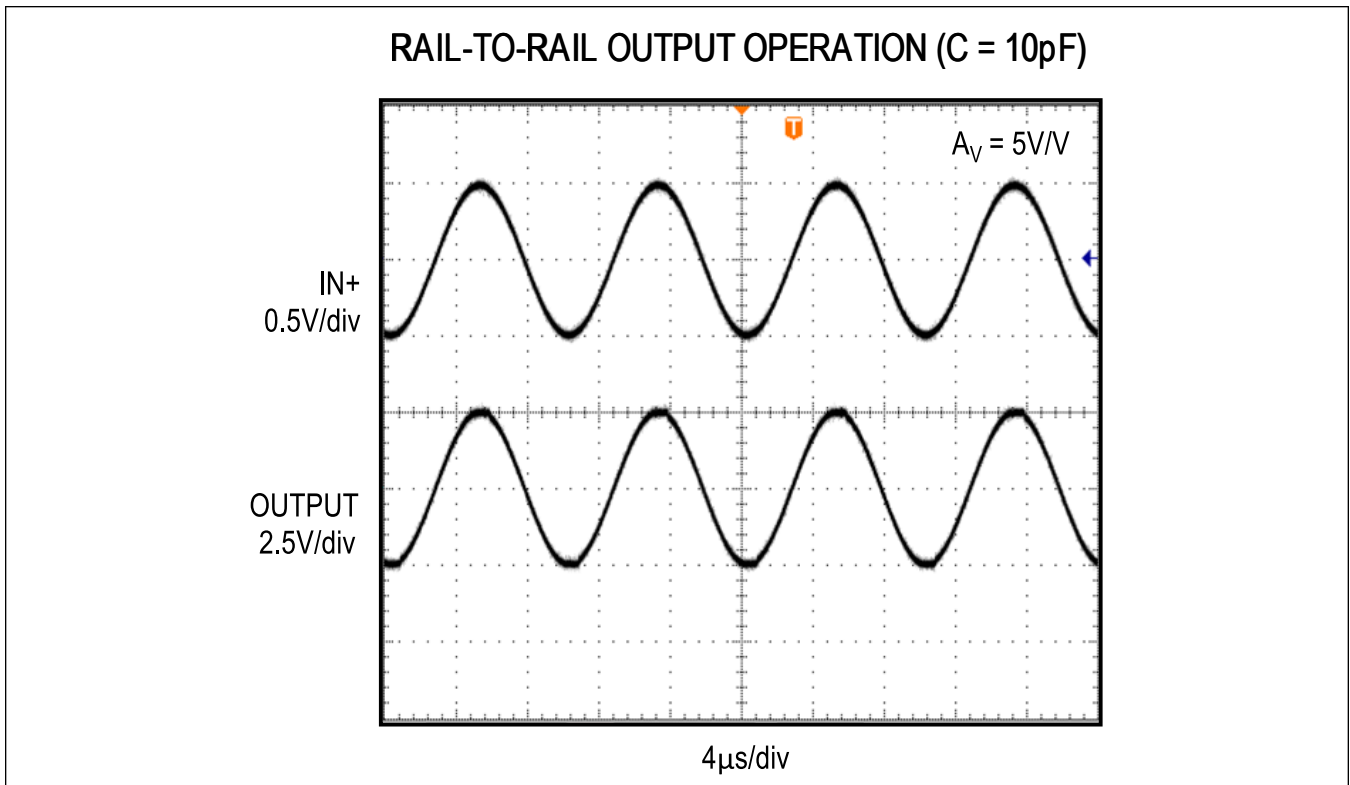
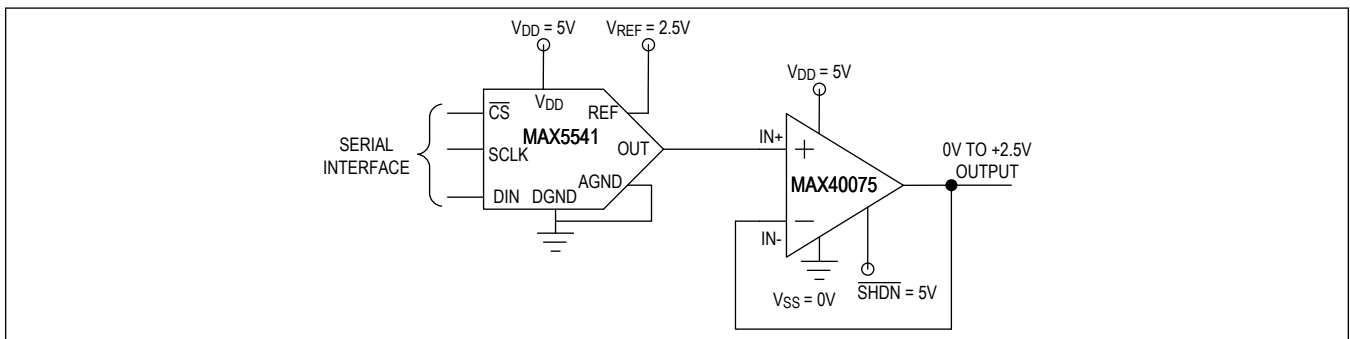


Figure 3. Rail-to-Rail Output Operation with 10kΩ and  $A_V = 5V/V$

**Chip Information**

PROCESS: BICMOS

**Typical Application Circuit**



## Ordering Information

PART NUMBER	TEMP RANGE	PIN-PACKAGE	STABLE GAIN (V/V)	BW (MHz)	TOP MARK
MAX40075AUT/V+T	-40°C to +125°C	6 SOT23	1	10	ACVK
MAX40075ANT+T	-40°C to +125°C	6 WLP	1	10	—
MAX40075AUT+T	-40°C to +125°C	6 SOT23	1	10	ACVD
MAX40088ANT+T	-40°C to +125°C	6 WLP	5	42	—
MAX40088AUT+T	-40°C to +125°C	6 SOT23	5	42	ACVE

+ Denotes a lead(Pb)-free/RoHS-compliant package.

T Denotes tape-and-reel.

/V denotes an automotive qualified part.